

HD74HC323

8-bit Universal Shift/Storage Register (with 3-state Outputs)

REJ03D0610-0200
(Previous ADE-205-489)
Rev.2.00
Jan 31, 2006

Description

This eight-bit universal register features multiplexed I/O ports to achieve full eight bit data handling in a single 20-pin package. HD74HC323 applications are as stacked or push-down registers, buffer storage, and accumulator registers.

Two function-select inputs and two output control inputs can be used to choose the modes of operation listed in the function table.

Synchronous parallel loading is accomplished by taking both function-select lines S_0 and S_1 high. This places the three-state outputs in a high-impedance state, which permits data that is applied on the I/O ports to be clocked into the register. Reading out of this register can be accomplished while the outputs are enabled in any mode. The clear function is synchronous, and a low level at the clear input clears the register on the next low-to-high transition of the clock.

Features

- High Speed Operation: t_{pd} (Clock to Q) = 20 ns typ ($C_L = 50$ pF)
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2$ to 6 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max ($T_a = 25^\circ\text{C}$)
- Ordering Information

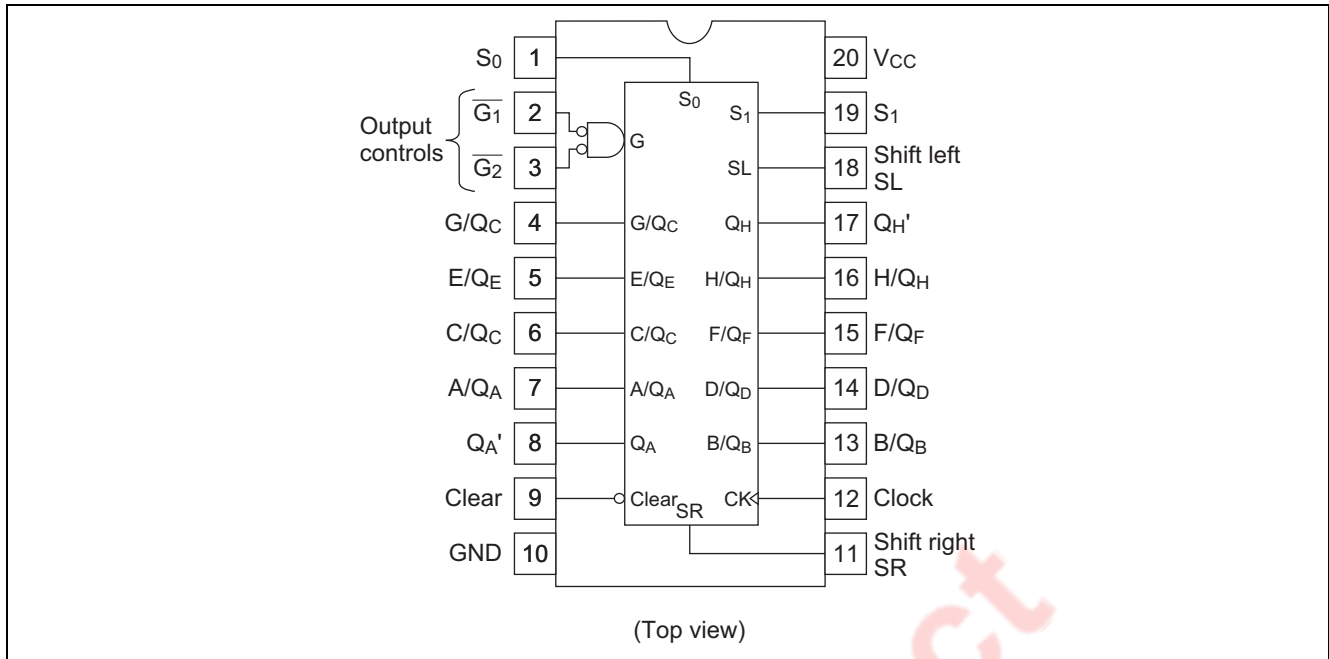
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC323RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)

Function Table

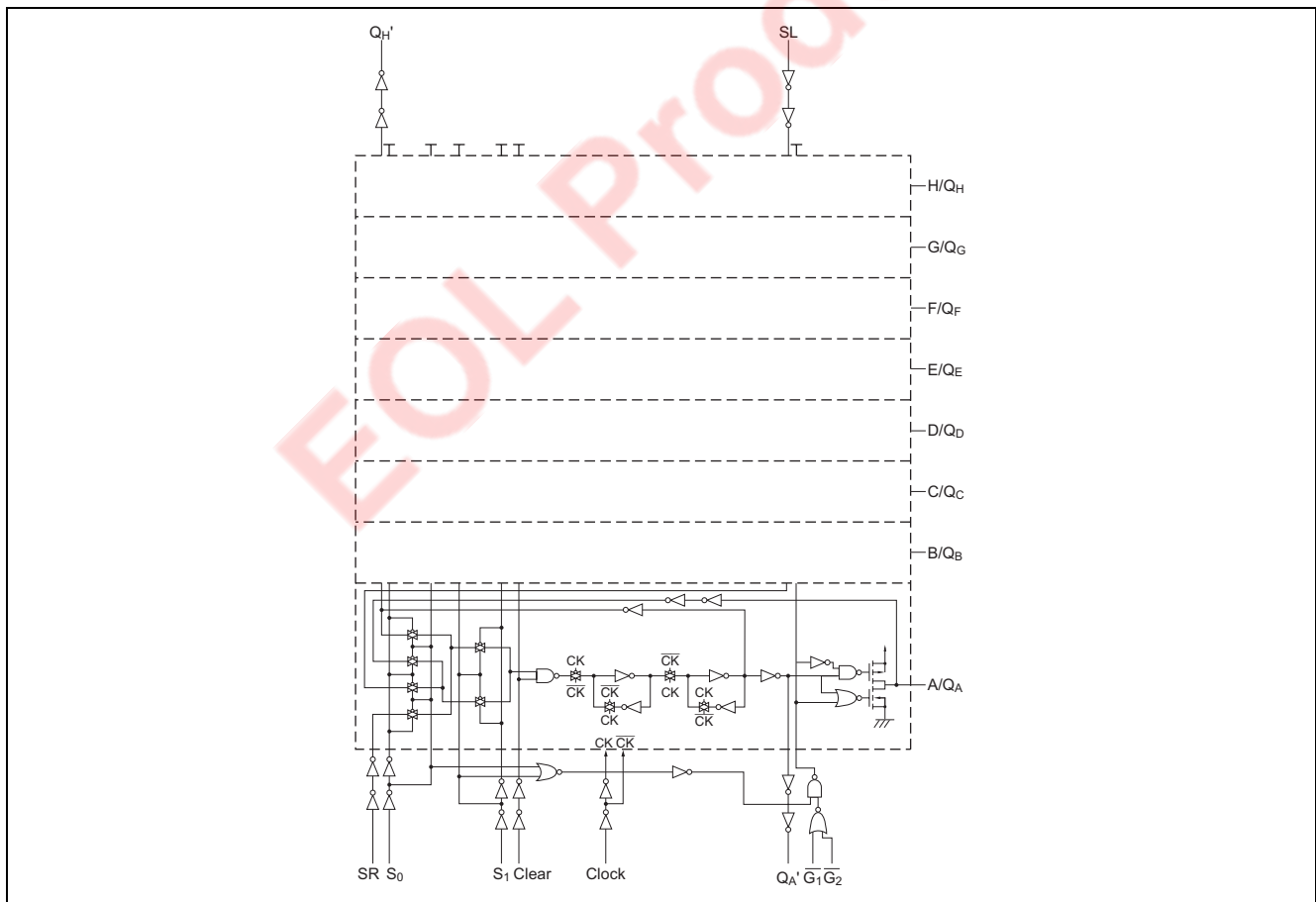
Mode	Inputs								Inputs/Outputs								Outputs	
	Clear	Function Select		Output Control		Clock	Serial											
		S ₁	S ₀	$\overline{G}_1\uparrow$	$\overline{G}_2\uparrow$		S _L	S _R	A/Q _A	B/Q _B	C/Q _C	D/Q _D	E/Q _E	F/Q _F	G/Q _G	H/Q _H	Q _A '	Q _H '
Clear	L	X	L	L	L		X	X	L	L	L	L	L	L	L	L	L	L
	L	L	X	L	L		X	X	L	L	L	L	L	L	L	L	L	L
Hold	H	L	L	L	L	X	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}	Q _{E0}	Q _{F0}	Q _{G0}	Q _{H0}	Q _{A0}	Q _{H0}
	H	X	X	L	L	L	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}	Q _{E0}	Q _{F0}	Q _{G0}	Q _{H0}	Q _{A0}	Q _{H0}
Shift Right	H	L	H	L	L		X	H	H	Q _{An}	Q _{Bn}	Q _{Cn}	Q _{Dn}	Q _{En}	Q _{Fn}	Q _{Gn}	H	Q _{Gn}
	H	L	H	L	L		X	L	L	Q _{An}	Q _{Bn}	Q _{Cn}	Q _{Dn}	Q _{En}	Q _{Fn}	Q _{Gn}	L	Q _{Gn}
Shift Left	H	H	L	L	L		H	X	Q _{Bn}	Q _{Cn}	Q _{Dn}	Q _{En}	Q _{Fn}	Q _{Gn}	Q _{Hn}	H	Q _{Bn}	H
	H	H	L	L	L		L	X	Q _{Bn}	Q _{Cn}	Q _{Dn}	Q _{En}	Q _{Fn}	Q _{Gn}	Q _{Hn}	L	Q _{Bn}	L
Load	H	H	H	X	X		X	X	a	b	c	d	e	f	g	h	a	h

a ... h = the level of the steady-state input at A through H, respectively. These data are loaded into the flip-flops while the flip-flop outputs are isolated from the input/output terminals.

Pin Arrangement



Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
Input / Output voltage	V_{IN}, V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input / Output diode current	I_{IK}, I_{OK}	± 20	mA
Output current	I_{OUT}	± 35	mA
V_{CC} , GND current	I_{CC} or I_{GND}	± 75	mA
Power dissipation	P_T	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	2 to 6	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V_{CC}	V	
Operating temperature	Ta	-40 to 85	°C	
Input rise / fall time ^{*1}	t_r, t_f	0 to 1000	ns	$V_{CC} = 2.0$ V
		0 to 500		$V_{CC} = 4.5$ V
		0 to 400		$V_{CC} = 6.0$ V

Note: 1. This item guarantees maximum limit when one input switches.

Electrical Characteristics

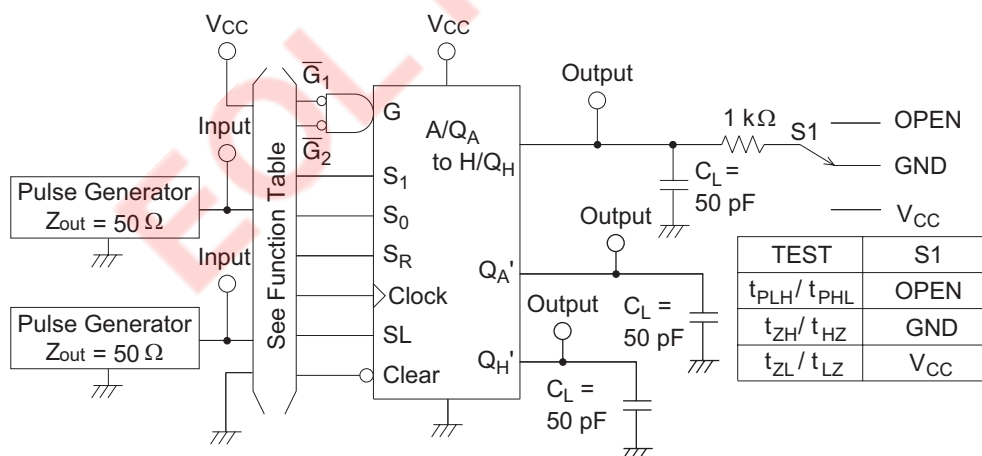
Item	Symbol	V_{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V_{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V_{IL}	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V_{OH}	2.0	1.9	2.0	—	1.9	—	V	$V_{in} = V_{IH}$ or V_{IL}	$I_{OH} = -20$ μ A
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	—	—	4.13	—		Q_A to Q_H	$I_{OH} = -6$ mA
		6.0	5.68	—	—	5.63	—			$I_{OH} = -7.8$ mA
		4.5	4.18	—	—	4.13	—		Q_A', Q_H'	$I_{OH} = -4$ mA
		6.0	5.68	—	—	5.63	—			$I_{OH} = -5.2$ mA
	V_{OL}	2.0	—	0.0	0.1	—	0.1	V	$V_{in} = V_{IH}$ or V_{IL}	$I_{OL} = 20$ μ A
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33		Q_A to Q_H	$I_{OL} = 6$ mA
		6.0	—	—	0.26	—	0.33			$I_{OL} = 7.8$ mA
		4.5	—	—	0.26	—	0.33		Q_A', Q_H'	$I_{OL} = 4$ mA
		6.0	—	—	0.26	—	0.33			$I_{OL} = 5.2$ mA
Off-state output current	I_{OZ}	6.0	—	—	± 0.5	—	± 5.0	μ A	$V_{in} = V_{IH}$ or V_{IL} , $V_{out} = V_{CC}$ or GND	
Input current	I_{in}	6.0	—	—	± 0.1	—	± 1.0	μ A	$V_{in} = V_{CC}$ or GND	
Quiescent supply current	I_{CC}	6.0	—	—	4.0	—	40	μ A	$V_{in} = V_{CC}$ or GND, $I_{out} = 0$ μ A	

Switching Characteristics

($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

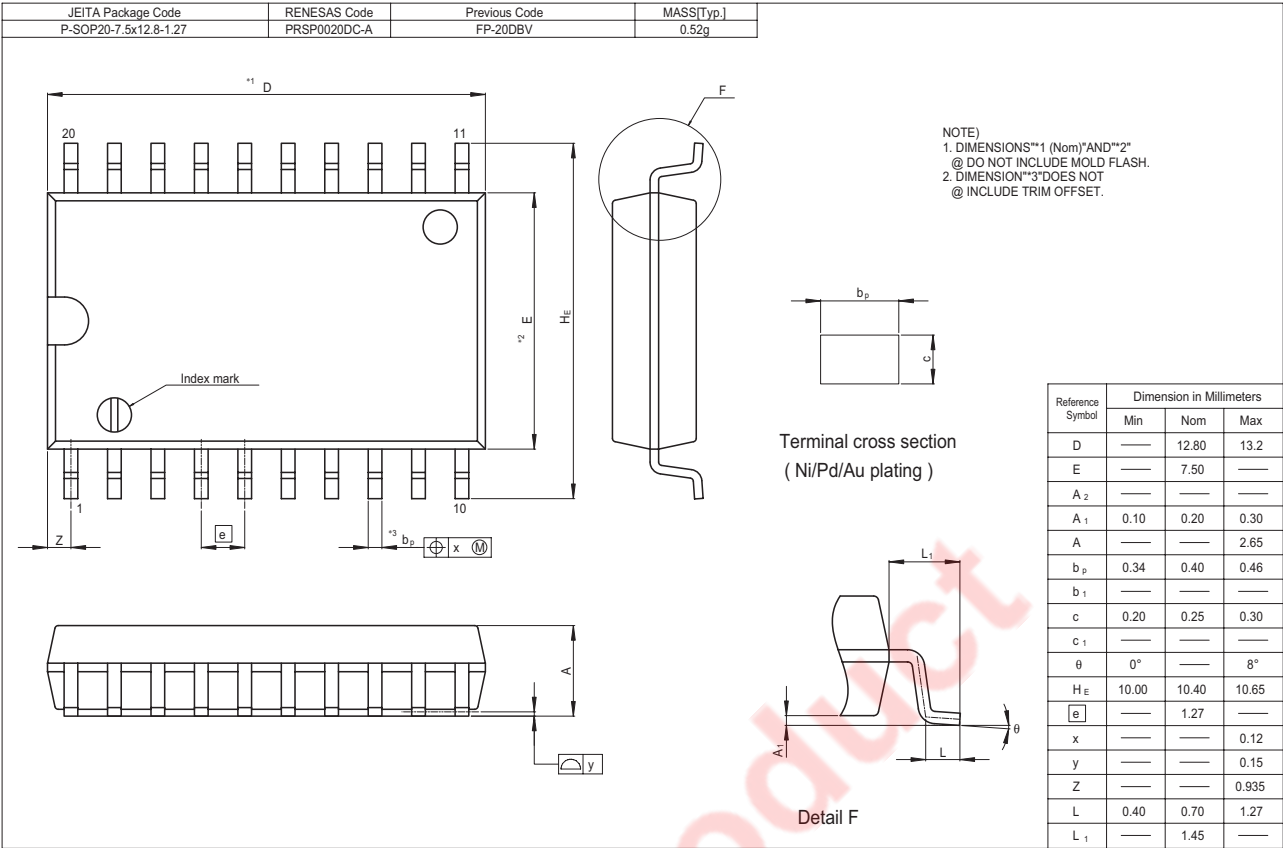
Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Maximum clock frequency	f _{max}	2.0	—	—	5	—	4	MHz	
		4.5	—	—	27	—	21		
		6.0	—	—	31	—	24		
Propagation delay time	t _{PLH} t _{PHL}	2.0	—	—	150	—	190	ns	Clock to Q _A ' or Q _H '
		4.5	—	18	30	—	38		
		6.0	—	—	26	—	33		
		2.0	—	—	175	—	220	ns	Clock to Q
		4.5	—	20	35	—	44		
		6.0	—	—	30	—	37		
Output enable time	t _{ZH} t _{ZL}	2.0	—	—	150	—	190	ns	
		4.5	—	14	30	—	38		
		6.0	—	—	26	—	33		
Output disable time	t _{HZ} t _{LZ}	2.0	—	—	150	—	190	ns	
		4.5	—	15	30	—	38		
		6.0	—	—	26	—	33		
Output rise/fall time	t _{TLH} t _{THL}	2.0	—	—	75	—	95	ns	Q _A ', Q _H '
		4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
		2.0	—	—	60	—	75	ns	Q
		4.5	—	4	12	—	15		
		6.0	—	—	10	—	13		
Input capacitance	C _{in}	—	—	5	10	—	10	pF	

Test Circuit



Note : 1. C_1 includes probe and jig capacitance.

Package Dimensions



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